XO-5-7-3.3V-LVPECL-xMHz LVPECL10 to 1450MHz Clock Oscillator

Features and Benefits

Frequency Range 10 MHz to 1450 MHz
Output Frequency to six decimal places
Output Frequency Examples: 12.688375 MHz; 125.345678 MHz
7 mm x 5.0 mm x 1.80 mm ceramic SMD 6-pad
±50 ppm total stability over -40°C to 85°C
1 to 1.5 pico-second phase jitter (12KHz to 20 MHz)
LVPECL outputs
3.3V supply

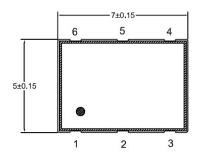
Typical Applications

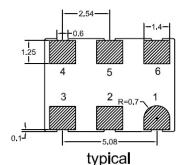
GbE Ethernet, SONET, Fibre channel, FPGA, and A/D clock reference devices

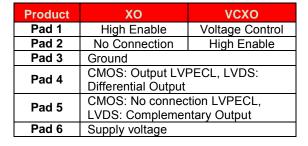
Description

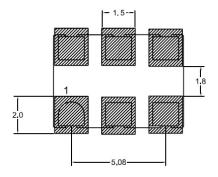
A new generation of low jitter / low power clock oscillators has been developed using the latest low noise integrated circuit topologies.

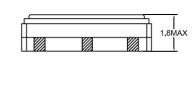
Mechanical Drawing & Pin Connections











bottom view

Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 USA TEL: 1-281-870-8822 EMAIL:Sales@DynamicEng.com

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Specifications

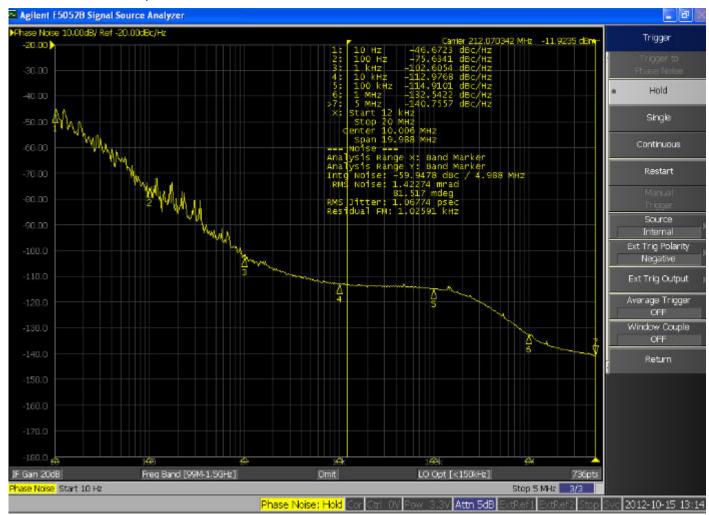
	: at Ta=+2	.5°C,		
Output Logic Type		LVPECL		
Frequency Range		10 ~ 1450 MHz		
Load		Differential		
Power Supply Voltage (V _{DD})		$V_{DD} = +3.3V \text{ D.C.} \pm 5\%$		
Output "High" Voltage;	V _{OH}	Voltage (V _{OD})		1.03 V Typical ,0.6 V max.
Output "Low" Voltage; V _{OL}		Voltage (V _{OD})		1.85 V Typical , 1.6 V min.
Frequency Stability		±50 ppm over -40°C to 85°C Over all conditions		
Duty Cycle		50% ± 5%		
Rise Time (Tr)/Fall Time (Tf) $(20\% V_{DD} - 80\% V_{DD})$		0.2nS. typ. 0.5nS. max.		
Current Consumption V _{DD} = +3.3V All values are typical and over operating temperatures.		100 MHz: 48 mA 250 MHz: 50 mA 500 MHz: 55 mA 750 MHz:59 mA 1 GHz:62 mA 1.35 GHz: 68 mA		
Current with Output Disabled		1.35 GHz: 68 mA 16 mA typical		
Start-up Time		10 ms max.		
Aging		±2 ppm max. first year at 25°C; ±10 ppm max. over 10 years		
Aging		Output Enable Fur		max. ever to years
OE Pad Input XOs: Pad 1 VCXOs: Pad 2		70% of V _{DD} minimum or no connection to enable output. LVCMOS/LVTTL level. 30% of V _{DD} maximum to disable output (high impedance). LVCMOS/LVTTL level.		
Output Enable Time		200 ns max.		
Output Disable Time		50 ns max.		
Output Disable Time				
•		Integrated Phase	Jitter	
Phase Jitter, rms (12 KHz to 20 MHz)	1.0 pS ty		Jitter	
Phase Jitter, rms	1.0 pS ty	Integrated Phase opical; 1.5 pS max.		
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms		Integrated Phase opical; 1.5 pS max. Environmental Performance	Specifica	
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms		Integrated Phase opical; 1.5 pS max. Environmental Performance	Specifica in accord	ance with EU Directive 2002/95/EC
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz)		Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2-55°C to 150°C	Specifica in accord	ance with EU Directive 2002/95/EC
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range Humidity	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2002/95/EC)	Specifica in accord	ance with EU Directive 2002/95/EC
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2-55°C to 150°C 85% RH, 85°C, 48 hours	Specifica e in accorda 2002/96/E0	ance with EU Directive 2002/95/EC
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range Humidity	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2-55°C to 150°C 85% RH, 85°C, 48 hours	Specifica e in accorda 2002/96/E0	ance with EU Directive 2002/95/EC
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range Humidity Fine Leak / Gross Leak Solderability Reflow	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2 -55°C to 150°C 85% RH, 85°C, 48 hours MIL-Std-883, method 1014, col MIL-STD-202F method 208E 260°C for 10 sec. 2X.	Specifica e in accorda 2002/96/E0 andition A /	MIL-Std-883, method 1014, condition C
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range Humidity Fine Leak / Gross Leak Solderability Reflow Vibration	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2 -55°C to 150°C 85% RH, 85°C, 48 hours MIL-Std-883, method 1014, com MIL-STD-202F method 208E 260°C for 10 sec. 2X. MIL-STD-202F method 204, 35	Specifica e in accorda 2002/96/E0 andition A /	MIL-Std-883, method 1014, condition C
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range Humidity Fine Leak / Gross Leak Solderability Reflow	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2-55°C to 150°C 85% RH, 85°C, 48 hours MIL-Std-883, method 1014, compliant MIL-STD-202F method 208E 260°C for 10 sec. 2X. MIL-STD-202F method 204, 35 MIL-STD-202F method 213B, to pick a sec. 23 MIL-STD-202F method 213B, to pick a sec. 24 MIL-STD-202F method 213B, to pick a sec. 24 MIL-STD-202F method 213B, to pick a sec. 25 MIL-STD-202F	Specifica e in accorda 2002/96/E0 andition A /	MIL-Std-883, method 1014, condition C
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range Humidity Fine Leak / Gross Leak Solderability Reflow Vibration Shock Resistance to Solvent	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2-55°C to 150°C 85% RH, 85°C, 48 hours MIL-Std-883, method 1014, com MIL-STD-202F method 208E 260°C for 10 sec. 2X. MIL-STD-202F method 204, 35 MIL-STD-202F method 213B, the MIL-STD-202, method 215	Specifica e in accorda 2002/96/E0 andition A /	MIL-Std-883, method 1014, condition C
Phase Jitter, rms (12 KHz to 20 MHz) Phase Jitter, rms (1.875 MHz to 20 MHz) ROHS Status Storage Temp. Range Humidity Fine Leak / Gross Leak Solderability Reflow Vibration Shock	< 100 fs	Integrated Phase opical; 1.5 pS max. Environmental Performance RoHS compliant, Pb (lead) free 6/6 (2002/95/EC) and WEEE (2-55°C to 150°C 85% RH, 85°C, 48 hours MIL-Std-883, method 1014, compliant MIL-STD-202F method 208E 260°C for 10 sec. 2X. MIL-STD-202F method 204, 35 MIL-STD-202F method 213B, to pick a sec. 23 MIL-STD-202F method 213B, to pick a sec. 24 MIL-STD-202F method 213B, to pick a sec. 24 MIL-STD-202F method 213B, to pick a sec. 25 MIL-STD-202F	Specifica e in accorda 2002/96/EC andition A /	MIL-Std-883, method 1014, condition C 000 Hz E, 1000GG ½ sine wave

Ordering Options:

"x MHz " examples : 125.000000 MHz ; or 12.688375 MHz ; 1250.005600 MHz

Phase Noise Graphs

212 MHz LVPECL output



1000 MHz LVPECL output

